



DPLS350Y

### **50V PNP LOW SATURATION POWER TRANSISTOR IN SOT89**

### **Features**

- BV<sub>CEO</sub> > -50V
- I<sub>C</sub> = -3A High Continuous Collector Current
- I<sub>CM</sub> up to -5A Peak Pulse Current
- 2W Power Dissipation
- Low Saturation Voltage V<sub>CE(sat)</sub> < -180mV @ 1A</li>
- $R_{CE(sat)} = 67m\Omega$  @ 2A for a Low Equivalent On-Resistance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

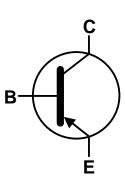
### **Mechanical Data**

- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.052 grams (Approximate)

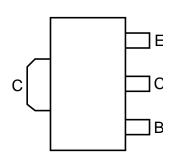
### **SOT89**



Top View



Device Symbol



Top View Pin-Out

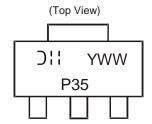
### Ordering Information (Note 4)

| Part Number  | Marking | Reel Size (inches) | Tape Width (mm) | Quantity per Reel |
|--------------|---------|--------------------|-----------------|-------------------|
| DPLS350Y-13  | P35     | 13                 | 12              | 2,500             |
| DPLS350Y-13R | P35     | 13                 | 12              | 4,000             |
| DPLS350YTC   | P35     | 13                 | 12              | 4,000             |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- ${\it 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.}\\$

## **Marking Information**



P35 = Product Type Marking Code: YWW = Date Code Marking Y = Last Digit of Year ex: 5 = 2015 WW = Week Code 01 - 53



### Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

| Characteristic               | Symbol           | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage       | V <sub>CBO</sub> | -50   | V    |
| Collector-Emitter Voltage    | V <sub>CEO</sub> | -50   | V    |
| Emitter-Base Voltage         | V <sub>EBO</sub> | -6    | V    |
| Continuous Collector Current | Ic               | -3    | Α    |
| Peak Pulse Current           | I <sub>CM</sub>  | -5    | Α    |
| Base Current                 | I <sub>B</sub>   | -500  | mA   |

### **Thermal Characteristics**

| Characteristic                                | Symbol                            | Value           | Unit |      |  |
|---|-----------------------------------|-----------------|------|------|--|
|   | (Note 5)                          |                 | 1    |      |  |
| Power Dissipation                             | (Note 6)                          | P <sub>D</sub>  | 1.6  | W    |  |
|   | (Note 7)                          |                 | 2.0  |      |  |
|   | (Note 5)                          |                 | 125  |      |  |
| Thermal Resistance, Junction to Ambient Air   | (Note 6)                          | $R_{	heta JA}$  | 78   | °C/W |  |
|   | (Note 7)                          |                 | 62.5 |      |  |
| Thermal Resistance, Junction to Lead (Note 8) |                                   | $R_{\theta JL}$ | 5.7  | °C/W |  |
| Operating and Storage Temperature Range       | T <sub>J</sub> , T <sub>STG</sub> | -55 to +150     | °C   |      |  |

# ESD Ratings (Note 9)

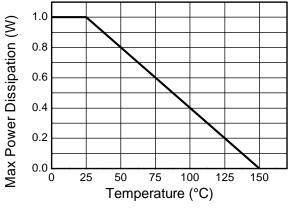
| Characteristic                             | Symbol  | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V    | 3A          |
| Electrostatic Discharge - Machine Model    | ESD MM  | 400   | V    | С           |

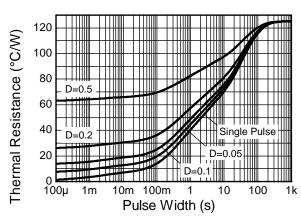
Notes:

- 5. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as note (5), except the device is mounted on 25mm x 25mm 1oz copper.
- 7. Same as note (5), except the device is mounted on 50mm x 50mm 1oz copper.
- 8. Thermal resistance from junction to solder-point (on the exposed collector pad).
  9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



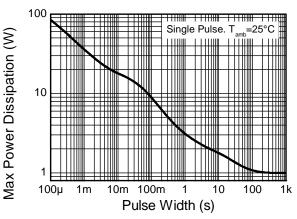
## **Thermal Characteristics and Derating Information**



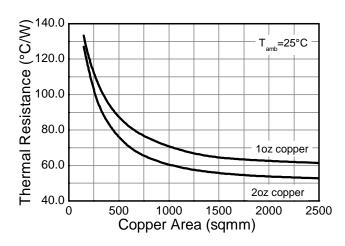


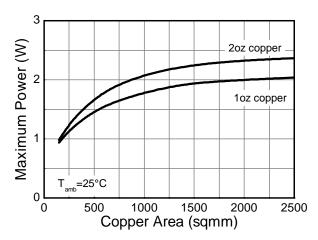
**Derating Curve** 

**Transient Thermal Impedance** 



**Pulse Power Dissipation** 





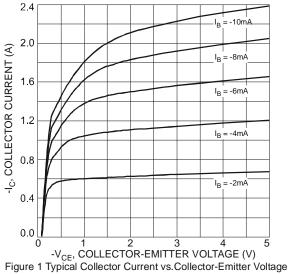


## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                                  | Symbol               | Min | Тур | Max  | Unit | Test Condition   |
|---|----------------------|-----|-----|------|------|--|
| Collector-Base Breakdown Voltage                | BV <sub>CBO</sub>    | -50 | _   | _    | V    | I <sub>C</sub> = -100μA                                      |
| Collector-Emitter Breakdown Voltage (Note 10)   | BV <sub>CEO</sub>    | -50 | _   | _    | V    | I <sub>C</sub> = -10mA                                       |
| Emitter-Base Breakdown Voltage                  | BV <sub>EBO</sub>    | -6  | _   | _    | V    | $I_E = -100 \mu A$   |
| Collector-Emitter Cut-off Current               | I <sub>CES</sub>     | _   | _   | -100 | nA   | V <sub>CE</sub> = -50V                                       |
| Collector Cut-off Current                       | I <sub>CBO</sub>     | _   | 1   | -100 | nA   | V <sub>CB</sub> = -50V                                       |
| Collector Cut-on Current                        |                      |     |     | -50  | μA   | V <sub>CB</sub> = -50V, T <sub>A</sub> = +150°C              |
| Emitter Cut-off Current                         | I <sub>EBO</sub>     | _   | _   | -100 | nA   | V <sub>EB</sub> = -5V  |
|   |                      | 200 |     | _    |      | I <sub>C</sub> = -100mA, V <sub>CE</sub> = -2V               |
|   |                      | 200 |     | _    |      | I <sub>C</sub> = -500mA, V <sub>CE</sub> = -2V               |
| Static Forward Current Transfer Ratio (Note 10) | h <sub>FE</sub>      | 200 | _   | 450  | _    | I <sub>C</sub> = -1A, V <sub>CE</sub> = -2V                  |
|   |                      | 130 | -   | _    |      | I <sub>C</sub> = -2A, V <sub>CE</sub> = -2V                  |
|   |                      | 80  |     | _    |      | $I_C = -3A$ , $V_{CE} = -2V$                                 |
|   |                      |     | _   | -90  |      | I <sub>C</sub> = -500mA, I <sub>B</sub> = -50mA              |
|   |                      | _   |     | -180 | m∨   | $I_C = -1A$ , $I_B = -50mA$                                  |
| Collector-Emitter Saturation Voltage (Note 10)  | VCE(sat)             |     |     | -320 |      | I <sub>C</sub> = -2A, I <sub>B</sub> = -100mA                |
|   |                      |     |     | -270 |      | $I_C = -2A$ , $I_B = -200mA$                                 |
|   |                      |     |     | -390 |      | $I_C = -3A$ , $I_B = -300mA$                                 |
| Equivalent On-Resistance                        | R <sub>CE(sat)</sub> | 1   | 67  | 135  | mΩ   | $I_C = -2A$ , $I_B = -200mA$                                 |
| Base-Emitter Saturation Voltage (Note 10)       | V <sub>BE(sat)</sub> | _   | _   | -1.1 | V    | $I_C = -2A$ , $I_B = -100mA$                                 |
| Base-Emilier Saturation voltage (Note 10)       |                      |     |     | -1.2 |      | $I_C = -3A$ , $I_B = -300mA$                                 |
| Base-Emitter Turn-On Current (Note 10)          | V <sub>BE(on)</sub>  | 1   | _   | -1.1 | V    | $I_C = -1A, V_{CE} = -2V$                                    |
| Transition Frequency                            | f⊤                   | 100 | _   | -    | MHz  | $I_C = -100 \text{mA}, V_{CE} = -5 \text{V},$<br>f = 100 MHz |
| Collector Output Capacitance                    | C <sub>obo</sub>     | _   | _   | 35   | pF   | V <sub>CB</sub> = -10V, I <sub>E</sub> = 0, f = 1MHz         |
| Turn-On Time                                    | t <sub>(ON)</sub>    | _   | 87  | _    | ns   |  |
| Delay Time                                      | t <sub>D</sub>       | _   | 41  | _    | ns   |  |
| Rise Time                                       | t <sub>R</sub>       | _   | 46  | _    | ns   | $V_{CC} = -30v$ ,  |
| Turn-Off Time                                   | t <sub>(OFF)</sub>   | _   | 294 | _    | ns   | $I_{CC} = 150 \text{mA}$<br>$I_{B1} = I_{B2} = 15 \text{mA}$ |
| Storage Time                                    | ts                   | _   | 250 | _    | ns   | - 182 = 13111A   |
| Fall Time                                       | t <sub>F</sub>       | _   | 44  | _    | ns   |  |

Note: 10. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.





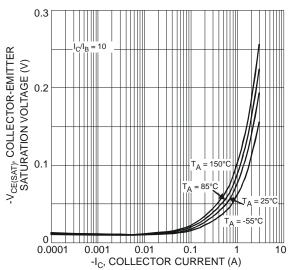


Figure 3 Typical Collector-Emitter Saturation Voltage vs. Collector Current

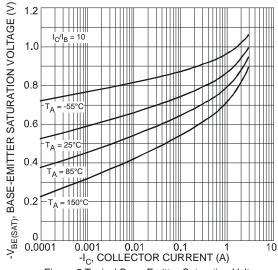
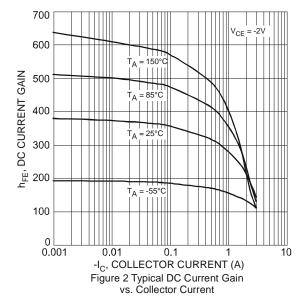
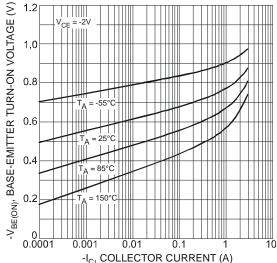


Figure 5 Typical Base-Emitter Saturation Voltage vs. Collector Current





-I<sub>C</sub>, COLLECTOR CURRENT (A) Figure 4 Typical Base-Emitter Turn-On Voltage vs. Collector Current

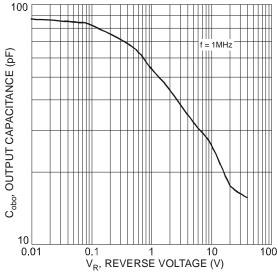
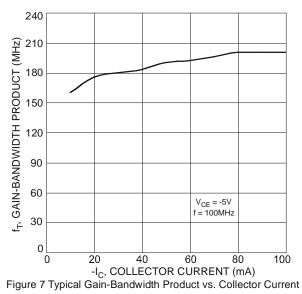


Figure 6 Typical Output Capacitance Characteristics



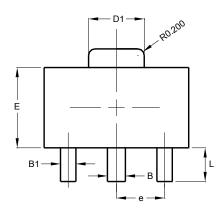


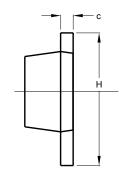


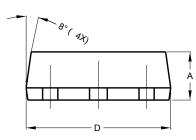
# **Package Outline Dimensions**

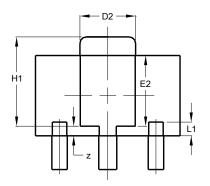
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

### **SOT89**







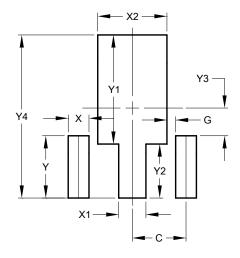


| SOT89                |       |       |       |  |  |
|----------------------|-------|-------|-------|--|--|
| Dim                  | Min   | Max   | Тур   |  |  |
| Α                    | 1.40  | 1.60  | 1.50  |  |  |
| В                    | 0.50  | 0.62  | 0.56  |  |  |
| B1                   | 0.42  | 0.54  | 0.48  |  |  |
| С                    | 0.35  | 0.43  | 0.38  |  |  |
| D                    | 4.40  | 4.60  | 4.50  |  |  |
| D1                   | 1.62  | 1.83  | 1.733 |  |  |
| D2                   | 1.61  | 1.81  | 1.71  |  |  |
| Е                    | 2.40  | 2.60  | 2.50  |  |  |
| E2                   | 2.05  | 2.35  | 2.20  |  |  |
| е                    | -     | -     | 1.50  |  |  |
| Н                    | 3.95  | 4.25  | 4.10  |  |  |
| H1                   | 2.63  | 2.93  | 2.78  |  |  |
| L                    | 0.90  | 1.20  | 1.05  |  |  |
| L1                   | 0.327 | 0.527 | 0.427 |  |  |
| Z                    | 0.20  | 0.40  | 0.30  |  |  |
| All Dimensions in mm |       |       |       |  |  |

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

### SOT89



| Dimensions | Value   |  |  |
|------------|---------|--|--|
|            | (in mm) |  |  |
| С          | 1.500   |  |  |
| G          | 0.244   |  |  |
| X          | 0.580   |  |  |
| X1         | 0.760   |  |  |
| X2         | 1.933   |  |  |
| Y          | 1.730   |  |  |
| Y1         | 3.030   |  |  |
| Y2         | 1.500   |  |  |
| Y3         | 0.770   |  |  |
| Y4         | 4.530   |  |  |



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